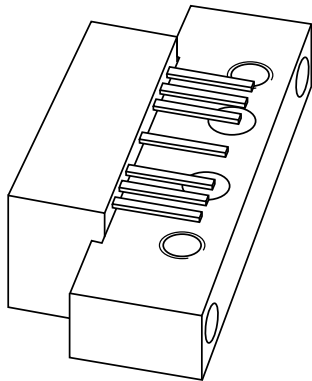


# DATA SHEET



## **BGD712**

750 MHz, 18.5 dB gain power  
doubler amplifier

Product specification  
Supersedes data of 2001 Oct 29

2001 Nov 02



# 750 MHz, 18.5 dB gain power doubler amplifier

**BGD712**

## FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

## APPLICATIONS

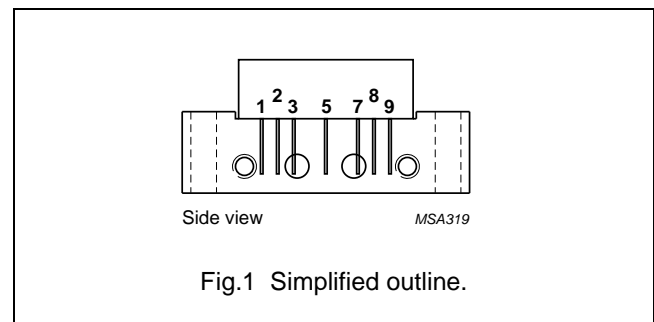
- CATV systems operating in the 40 to 750 MHz frequency range.

## DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

## PINNING - SOT115J

| PIN  | DESCRIPTION     |
|------|-----------------|
| 1    | input           |
| 2, 3 | common          |
| 5    | +V <sub>B</sub> |
| 7, 8 | common          |
| 9    | output          |



## QUICK REFERENCE DATA

| SYMBOL           | PARAMETER                      | CONDITIONS            | MIN. | MAX. | UNIT |
|------------------|--------------------------------|-----------------------|------|------|------|
| G <sub>p</sub>   | power gain                     | f = 45 MHz            | 18.2 | 18.8 | dB   |
|                  |                                | f = 750 MHz           | 19   | 20   | dB   |
| I <sub>tot</sub> | total current consumption (DC) | V <sub>B</sub> = 24 V | 380  | 410  | mA   |

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL           | PARAMETER                           | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|------|------|------|
| V <sub>B</sub>   | supply voltage                      | –    | 30   | V    |
| V <sub>i</sub>   | RF input voltage                    | –    | 70   | dBmV |
| T <sub>stg</sub> | storage temperature                 | –40  | +100 | °C   |
| T <sub>mb</sub>  | operating mounting base temperature | –20  | +100 | °C   |

750 MHz, 18.5 dB gain power doubler amplifier

BGD712

**CHARACTERISTICS**

Bandwidth 40 to 750 MHz;  $V_B = 24\text{ V}$ ;  $T_{mb} = 35\text{ °C}$ ;  $Z_S = Z_L = 75\ \Omega$

| SYMBOL           | PARAMETER              | CONDITIONS  | MIN. | TYP. | MAX.  | UNIT |
|------------------|------------------------|---|------|------|-------|------|
| G <sub>p</sub>   | power gain             | f = 45 MHz  | 18.2 | 18.5 | 18.8  | dB   |
|                  |                        | f = 750 MHz   | 19   | 19.5 | 20    | dB   |
| SL               | slope straight line    | f = 45 to 750 MHz; note 1   | 0.5  | 1    | 1.5   | dB   |
| FL               | flatness straight line | f = 45 to 100 MHz   | –    | –    | ±0.35 | dB   |
|                  |                        | f = 100 to 700 MHz  | –    | –    | ±0.5  | dB   |
|                  |                        | f = 700 to 750 MHz  | –    | –    | ±0.15 | dB   |
| S <sub>11</sub>  | input return losses    | f = 45 to 80 MHz  | 23   | –    | –     | dB   |
|                  |                        | f = 80 to 160 MHz   | 23   | –    | –     | dB   |
|                  |                        | f = 160 to 320 MHz  | 21   | –    | –     | dB   |
|                  |                        | f = 320 to 550 MHz  | 20   | –    | –     | dB   |
|                  |                        | f = 550 to 650 MHz  | 20   | –    | –     | dB   |
|                  |                        | f = 650 to 750 MHz  | 19   | –    | –     | dB   |
|                  |                        | f = 750 to 790 MHz  | 17   | –    | –     | dB   |
| S <sub>22</sub>  | output return losses   | f = 45 to 80 MHz  | 23   | –    | –     | dB   |
|                  |                        | f = 80 to 160 MHz   | 23   | –    | –     | dB   |
|                  |                        | f = 160 to 320 MHz  | 20   | –    | –     | dB   |
|                  |                        | f = 320 to 550 MHz  | 20   | –    | –     | dB   |
|                  |                        | f = 550 to 650 MHz  | 19   | –    | –     | dB   |
|                  |                        | f = 650 to 750 MHz  | 19   | –    | –     | dB   |
|                  |                        | f = 750 to 790 MHz  | 17   | –    | –     | dB   |
| S <sub>21</sub>  | phase response         | f = 50 MHz  | –45  | –    | +45   | deg  |
| CTB              | composite triple beat  | 112 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 745.25 MHz                | –    | –    | –62   | dB   |
|                  |                        | 79 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 547.25 MHz                 | –    | –    | –68   | dB   |
|                  |                        | 79 channels; f <sub>m</sub> = 445.25 MHz; V <sub>o</sub> = 49.3 dBmV at 547 MHz; note 2 | –    | –    | –63   | dB   |
| X <sub>mod</sub> | cross modulation       | 112 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz                 | –    | –    | –63   | dB   |
|                  |                        | 79 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz                  | –    | –    | –69   | dB   |
|                  |                        | 79 channels; f <sub>m</sub> = 745.25 MHz; V <sub>o</sub> = 49.3 dBmV at 547 MHz; note 2 | –    | –    | –60   | dB   |

# 750 MHz, 18.5 dB gain power doubler amplifier

BGD712

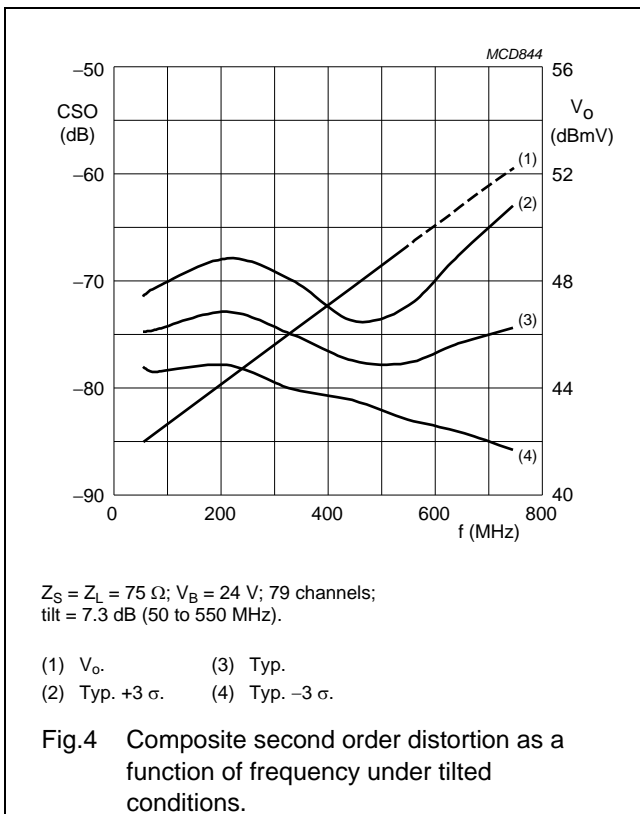
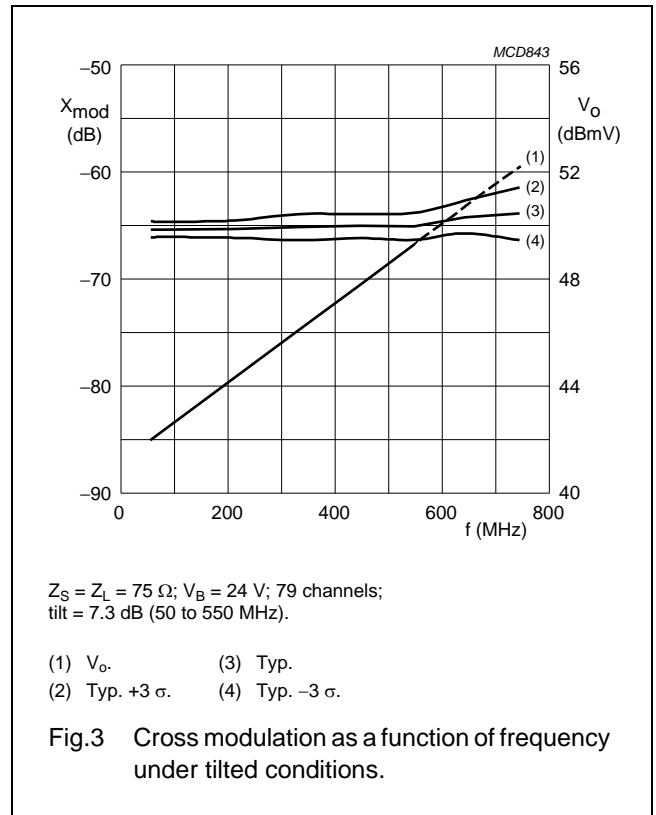
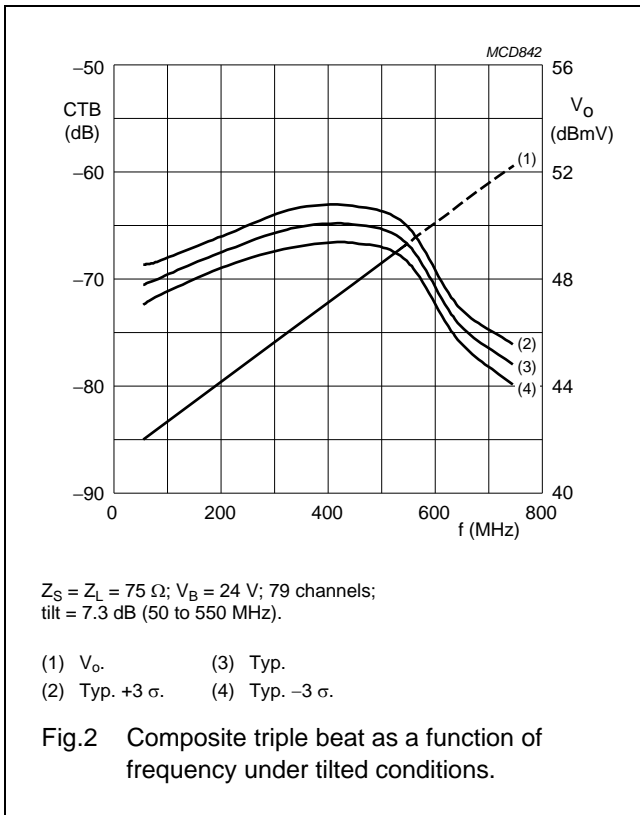
| SYMBOL    | PARAMETER                         | CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|-----------|-----------------------------------|---|------|------|------|------|
| CSO       | composite second order distortion | 112 channels flat; $V_o = 44$ dBmV;<br>$f_m = 746.5$ MHz                | –    | –    | –63  | dB   |
|           |                                   | 79 channels flat; $V_o = 44$ dBmV;<br>$f_m = 548.5$ MHz                 | –    | –    | –68  | dB   |
|           |                                   | 79 channels; $f_m = 746.5$ MHz;<br>$V_o = 49.3$ dBmV at 547 MHz; note 2 | –    | –    | –62  | dB   |
| $d_2$     | second order distortion           | note 3  | –    | –    | –74  | dB   |
| $V_o$     | output voltage                    | $d_{im} = -60$ dB; note 4   | 64   | –    | –    | dBmV |
| NF        | noise figure                      | $f = 50$ MHz  | –    | –    | 5.5  | dB   |
|           |                                   | $f = 550$ MHz   | –    | –    | 5.5  | dB   |
|           |                                   | $f = 750$ MHz   | –    | –    | 7    | dB   |
| $I_{tot}$ | total current consumption (DC)    | note 5  | 380  | 395  | 410  | mA   |

## Notes

- Slope straight line is defined as gain at 750 MHz – gain at 45 MHz.
- Tilt = 7.3 dB (55 to 547 MHz).
- $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  
 $f_q = 691.25$  MHz;  $V_q = 44$  dBmV;  
measured at  $f_p + f_q = 746.5$  MHz.
- Measured according to DIN45004B:  
 $f_p = 740.25$  MHz;  $V_p = V_o$ ;  
 $f_q = 747.25$  MHz;  $V_q = V_o - 6$  dB;  
 $f_r = 749.25$  MHz;  $V_r = V_o - 6$  dB;  
measured at  $f_p + f_q - f_r = 738.25$  MHz.
- The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

# 750 MHz, 18.5 dB gain power doubler amplifier

BGD712



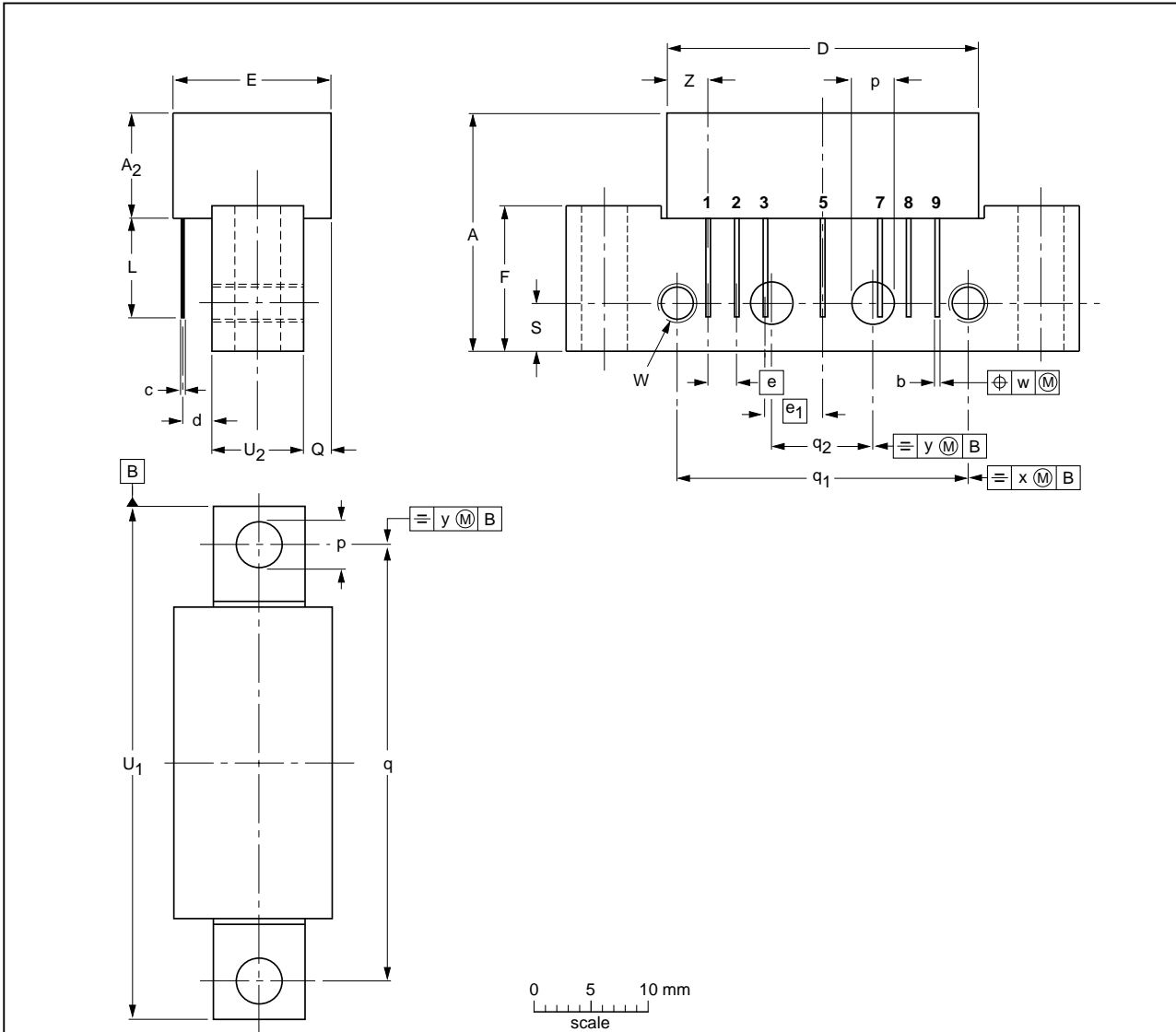
750 MHz, 18.5 dB gain power doubler amplifier

BGD712

PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

| UNIT | A max. | A <sub>2</sub> max. | b            | c    | D max. | d            | E max. | e    | e <sub>1</sub> | F    | L min. | p            | Q max. | q    | q <sub>1</sub> | q <sub>2</sub> | S   | U <sub>1</sub> | U <sub>2</sub> | W           | w    | x   | y   | Z max. |
|------|--------|---------------------|--------------|------|--------|--------------|--------|------|----------------|------|--------|--------------|--------|------|----------------|----------------|-----|----------------|----------------|-------------|------|-----|-----|--------|
| mm   | 20.8   | 9.5                 | 0.51<br>0.38 | 0.25 | 27.2   | 2.04<br>2.54 | 13.75  | 2.54 | 5.08           | 12.7 | 8.8    | 4.15<br>3.85 | 2.4    | 38.1 | 25.4           | 10.2           | 4.2 | 44.75<br>44.25 | 8.2<br>7.8     | 6-32<br>UNC | 0.25 | 0.7 | 0.1 | 3.8    |

| OUTLINE VERSION | REFERENCES |       |       |  | EUROPEAN PROJECTION | ISSUE DATE           |
|-----------------|------------|-------|-------|--|---------------------|----------------------|
|                 | IEC        | JEDEC | JEITA |  |                     |                      |
| SOT115J         |            |       |       |  |                     | 04-02-04<br>10-06-18 |

# 750 MHz, 18.5 dB gain power doubler amplifier

BGD712

## DATA SHEET STATUS

| DOCUMENT STATUS <sup>(1)</sup> | PRODUCT STATUS <sup>(2)</sup> | DEFINITION  |
|--------------------------------|-------------------------------|---|
| Objective data sheet           | Development                   | This document contains data from the objective specification for product development. |
| Preliminary data sheet         | Qualification                 | This document contains data from the preliminary specification.                       |
| Product data sheet             | Production                    | This document contains the product specification.                                     |

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## 750 MHz, 18.5 dB gain power doubler amplifier

BGD712

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